



PJS6403

30V P-Channel Enhancement Mode MOSFET

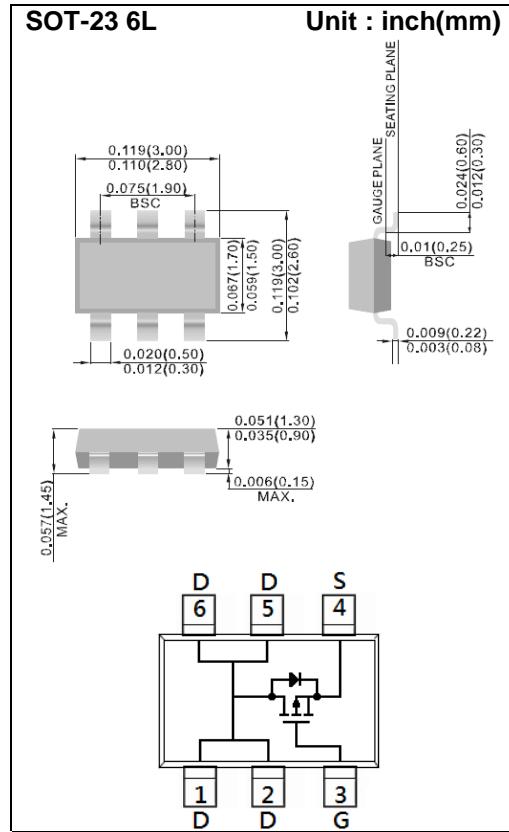
Voltage **-30 V** **Current** **-6.4A**

Features

- $R_{DS(ON)}$, $V_{GS} @ -10V$, $I_D @ -4A < 32m\Omega$
- $R_{DS(ON)}$, $V_{GS} @ -4.5V$, $I_D @ -2A < 46m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-23 6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0005 ounces, 0.014 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	+20	
Continuous Drain Current ^(Note 4)	I_D	-6.4	A
Pulsed Drain Current ^(Note 1,3)	I_{DM}	-46	
Power Dissipation	$T_a=25^\circ C$	2	W
	Derate above $25^\circ C$	16	$mW/\text{ }^\circ C$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150	$^\circ C$
Typical Thermal Resistance <ul style="list-style-type: none"> - Junction to Ambient ^(Note 5) 	$R_{\theta JA}$	62.5	$^\circ C/W$



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Electrical Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A$	-30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1	-1.6	-2.5	
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-4A$	-	27	32	$m\Omega$
		$V_{GS}=-4.5V, I_D=-2A$	-	38	46	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-30V, V_{GS}=0V$	-	-	-1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
Dynamic <small>(Note 6)</small>						
Total Gate Charge	Q_g	$V_{DS}=-15V, I_D=-5A,$ $V_{GS}=-4.5V$ <small>(Note 2,3)</small>	-	7.8	-	nC
Gate-Source Charge	Q_{gs}		-	2.7	-	
Gate-Drain Charge	Q_{gd}		-	2.8	-	
Input Capacitance	C_{iss}	$V_{DS}=-15V, V_{GS}=0V,$ $f=1MHz$	-	870	-	pF
Output Capacitance	C_{oss}		-	130	-	
Reverse Transfer Capacitance	C_{rss}		-	93	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-15V, I_D=-1A,$ $V_{GS}=-10V,$ $R_G=6\Omega$ <small>(Note 2,3)</small>	-	6.5	-	ns
Turn-On Rise Time	t_r		-	8.8	-	
Turn-Off Delay Time	$t_{d(off)}$		-	73	-	
Turn-Off Fall Time	t_f		-	44	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	-2	A
Diode Forward Voltage	V_{SD}	$I_S=-1A, V_{GS}=0V$		-0.75	-1	V

NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150^\circ C$. Ratings are based on low frequency and duty cycles to keep initial $T_J = 25^\circ C$.
4. The maximum current rating is package limited.
5. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing



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TYPICAL CHARACTERISTIC CURVES

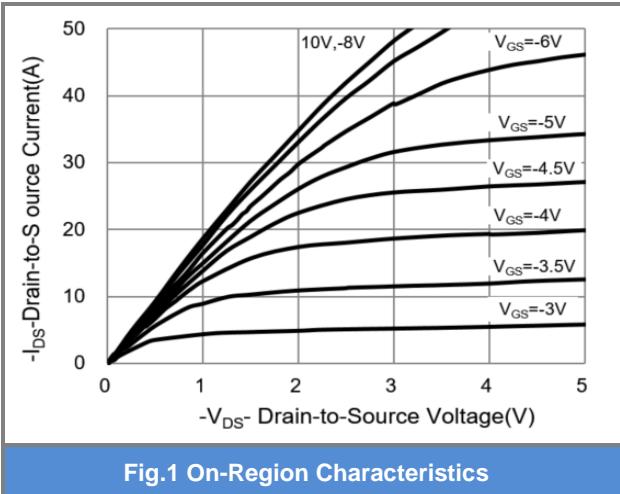


Fig.1 On-Region Characteristics

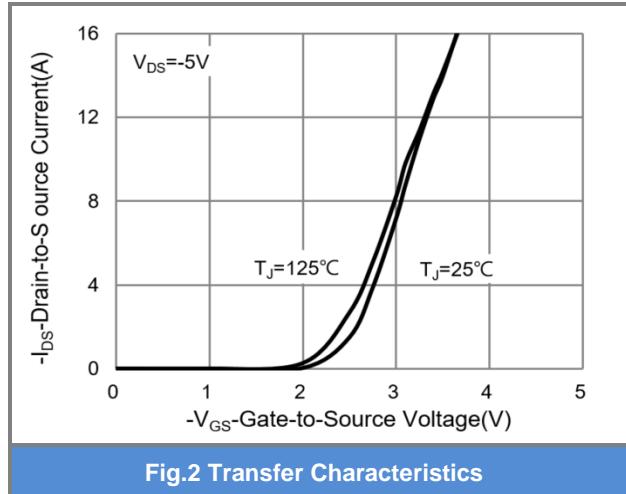


Fig.2 Transfer Characteristics

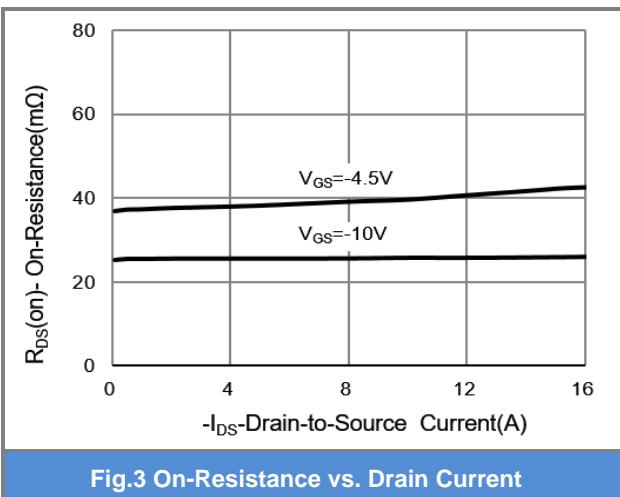


Fig.3 On-Resistance vs. Drain Current

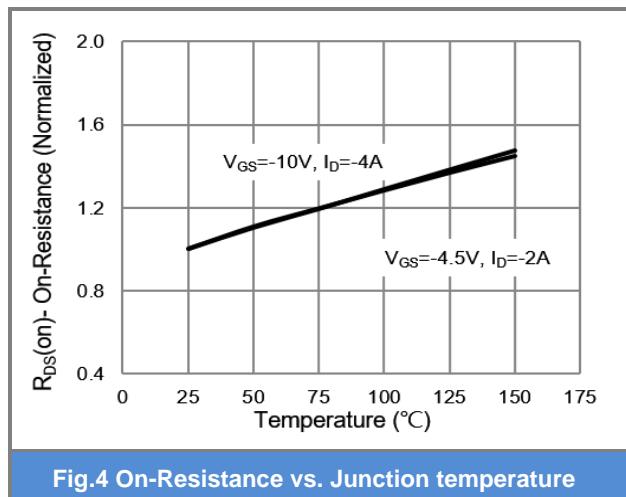


Fig.4 On-Resistance vs. Junction temperature

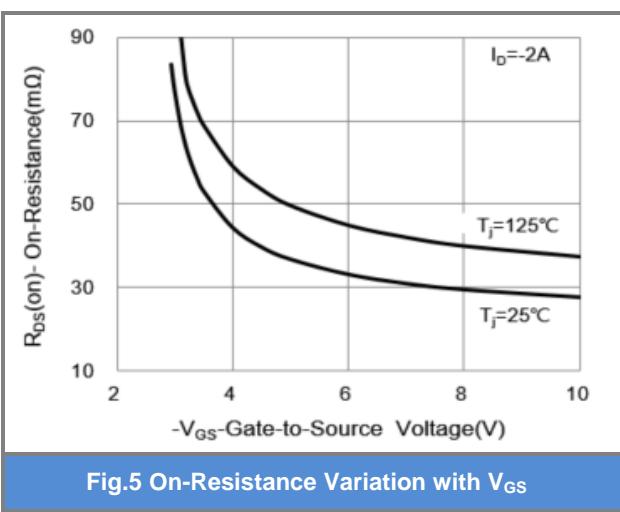


Fig.5 On-Resistance Variation with V_Gs

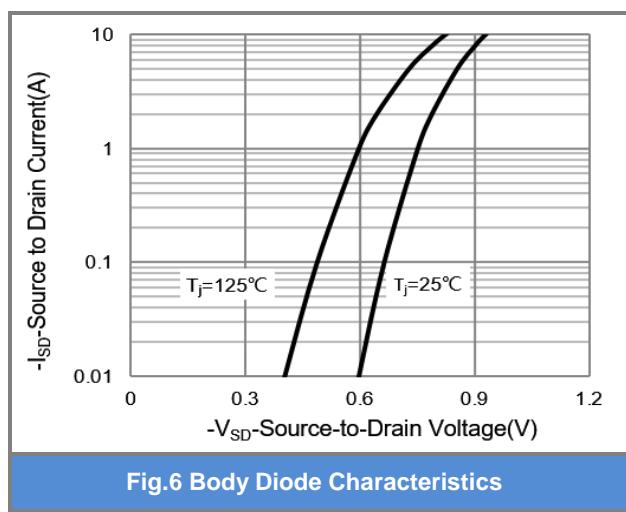


Fig.6 Body Diode Characteristics



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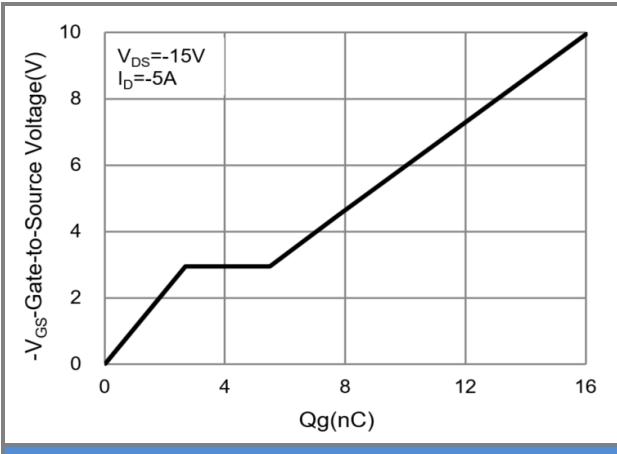


Fig.7 Gate-Charge Characteristics

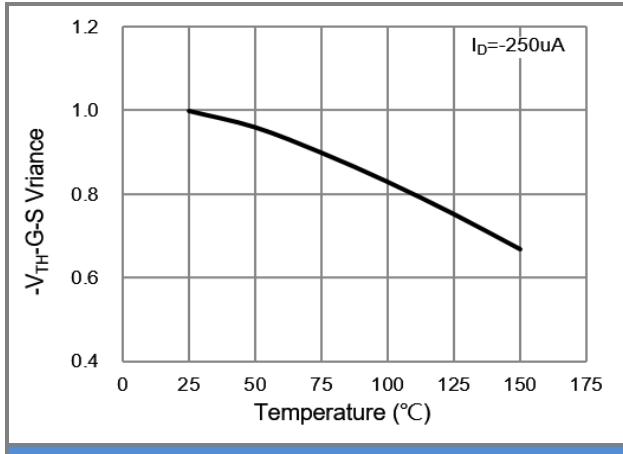


Fig.8 Threshold Voltage Variation with Temperature

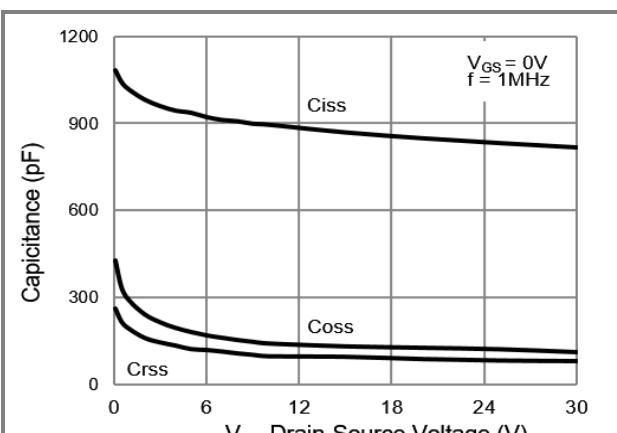


Fig.9 Capacitance vs. Drain-Source Voltage

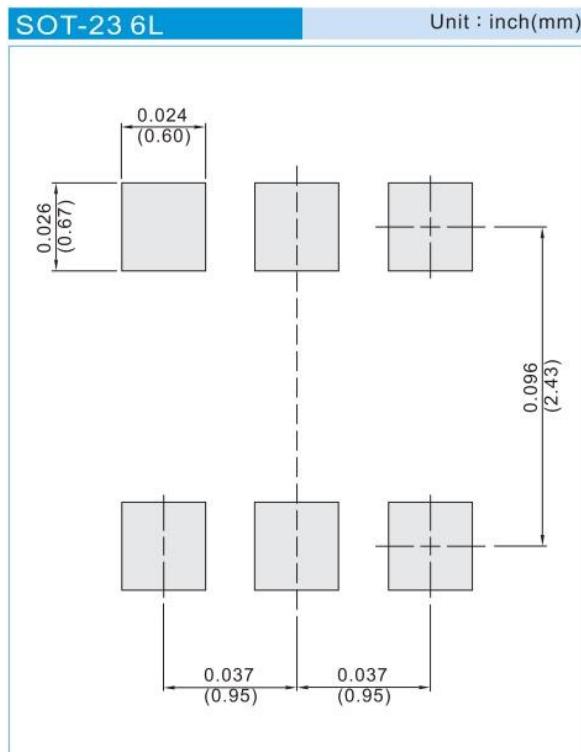


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Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJS6403_S1_00001	SOT-23 6L	3K pcs / 7" reel	S03	Halogen free

Mounting Pad Layout





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